Nuclear Instruments and Methods in Physics Research B46 (1989) 461–467
North-Holland

AUTHOR INDEX

Abonneau, E., see McHargue, C.J. B46 (1990) 74
Abonneau, E., G. Fuchs, M. Treilleux and A. Perez, Enhancement of copper–sapphire adhesion induced by ion beam mixing B46 (1990) 111
Al Ghamdi, A. and P.D. Townsend, Ion beam excited luminescence of sapphire B46 (1990) 133
Allen, A.M.T. and J.D. Comins, Defect aggregation in gamma-irradiated RbI using optical techniques B46 (1990) 240
Amaral, L., see Behar, M. B46 (1990) 313
Amaral, L., see Behar, M. B46 (1990) 350
Amoddeo, A., see Bonanno, A. B46 (1990) 456
Andreadis, T.D., see Hubler, G.K. B46 (1990) 384
Aono, K., M. Iwaki and S. Namba, Luminescence during Eu, Fe and Cr implantation into CaF_2 . . . . . B46 (1990) 220
Arnold, G.W. and R.R. Rye, Ion beam analysis of the effects of radiation on the chemical etching of poly(tetrafluorethylene) B46 (1990) 330

Balaji, V., D.E. David, T.F. Magnera, J. Michl and H.M. Urbassek, Sputtering yields of condensed rare gases . . B46 (1990) 435
Balanzat, E., see Toulemonde, M. B46 (1990) 64
Bassel, R.H., see Hubler, G.K. B46 (1990) 384
Behar, M., L. Amaral, J. Kaschny, F.C. Zawislak, R.B. Guimarães and D. Fink, Radiation induced diffusion of Xe implanted into the AZ1350 polymer B46 (1990) 313
Behar, M., see Fink, D. B46 (1990) 342
Behar, M., L. Amaral, F.C. Zawislak, R.B. Guimarães and D. Fink, Thermal stability and diffusion studies in the Au and Bi implanted AZ1350 photoresist B46 (1990) 350
Bénit, J. and W.L. Brown, Electronic sputtering of oxygen and water molecules from thin films of water ice bombarded by MeV Ne^+ ions B46 (1990) 448
Bernard, M., E. Rzepka and S. Lefrant, Electronic defects induced by X-rays in powders of alkaline iodides . . . B46 (1990) 235
Bernas, H., J. Lesueur, P. Nédellec, M.O. Ruault, L. Dumoulin and J.P. Burger, Ion beam irradiation studies of high temperature superconductors B46 (1990) 269
Bhatia, R.K., R.C. Singh and H.S. Virk, Anomalous behaviour of environment affected CR-39 at elevated temperatures B46 (1990) 358
Biersack, J.P., see Chadderton, L.T. B46 (1990) 46
Biersack, J.P. and R. Kallweit, Ion beam induced changes of the refractive index of PMMA B46 (1990) 309
Biersack, J.P., see Fink, D. B46 (1990) 342
Boatner, L.A., see McCallum, J.C. B46 (1990) 98
Boatner, L.A., see Farlow, G.C. B46 (1990) 422
Boiteux, G., see Davenas, J. B46 (1990) 317
Bonanno, A., A. Amoddeo and A. Oliva, Kinetic threshold in ion-induced electron emission from polycrystalline W B46 (1990) 456
Bouffard, S., see Toulemonde, M. B46 (1990) 64
Braunlich, P., S.C. Jones, X.-A. Shen, R.T. Casper and P. Kelly, Laser-induced modifications and the mechanism of intrinsic damage in wide gap optical materials B46 (1990) 224
Braunlich, P., see Casper, R.T. B46 (1990) 231
Brenier, R., see Romana, L. B46 (1990) 94
Brown, W.L., see Bénit, J. B46 (1990) 448
Brunel, M., see Romana, L. B46 (1990) 94
Burger, J.P., see Bernas, H. B46 (1990) 269

Calcagno, L., see Licciardello, A. B46 (1990) 338
Canut, B., see Romana, L. B46 (1990) 94
Canut, B., L. Romana, P. Thevenard and N. Moncoffre, Lattice disorder in α-Al_2O_3 induced by niobium implantation B46 (1990) 128
Cao, D.X., see Sood, D.K. B46 (1990) 194
Carosella, C.A., see Hubler, G.K. B46 (1990) 384
Cartz, L., see Karioris, F.G. B46 (1990) 176
Cartz, L., see Özkan, H. B46 (1990) 202

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(North-Holland)

Cartz, L., see Özkan, H. B46 (1990) 291
Casper, R.T., see Braunlich, P. B46 (1990) 224
Casper, R.T., S.C. Jones, P. Braunlich and P. Kelly, F-center accumulation as a mechanism of multiple-pulse, laser-induced bulk damage in KBr and KI at 532 nm B46 (1990) 231
Catlow, C.R.A., Defect structures in ionic materials B46 (1990) 52
Cavaille, J.Y., see Macchi, F. B46 (1990) 334
Cervellera, F., see Freire Jr., F.L. B46 (1990) 152
Chadderton, L.T., S. Ghosh, A. Saxena, K.K. Dwivedi, J.P. Biersack and D.W. Fink, On the origin of anomalous ranges of 1.65 GeV ^{132}Xe ions in muscovite mica B46 (1990) 46
Chandler, P.J., L. Zhang and P.D. Townsend, High temperature annealing of He^+ ion-implanted quartz optical waveguides B46 (1990) 69
Chase, L.L., Laser-induced surface ablation as a probe of optical surface damage mechanisms B46 (1990) 252
Chen, L.F., K.S. Song and C.H. Leung, The hopping motion of the off-center self-trapped excitons in alkali halide crystals B46 (1990) 216
Comins, J.D., see Allen, A.M.T. B46 (1990) 240

Danilovich, J., see Gärtner, K. B46 (1990) 405
Daudin, B., see Macchi, F. B46 (1990) 324
Daudin, B., see Macchi, F. B46 (1990) 334
Davenas, J., P. Thevenard, G. Boiteux, M. Fallavier and X.L. Lu, Hydrogenated carbon layers produced by ion beam irradiation of PMMA and polystyrene films B46 (1990) 317
Davenas, J., P. Thevenard and C. Khodr, Ion beam production of Cermets for selective absorption of solar energy B46 (1990) 417
David, D.E., see Balaji, V. B46 (1990) 435
Davies, J.A., see Macaulay-Newcombe, R.G. B46 (1990) 180
Della Mea, G., see Mariotto, G. B46 (1990) 107
Della Mea, G., see Freire Jr., F.L. B46 (1990) 152
Della Mea, G., see Matzke, Hj. B46 (1990) 256
Derry, T.E., see Luyckx, S.B. B46 (1990) 36
Devine, R.A.B., Radiation damage and the role of structure in amorphous SiO_2 . . . . . B46 (1990) 244
Devine, R.A.B., On the physical models of annealing of radiation induced defects in amorphous SiO_2 . . . . . B46 (1990) 261
Donnet, C., H. Jaffrezic, N. Moncoffre, J. Tousset and G. Fuchs, Characterization of polycrystalline α-Al_2O_3 zirconium implanted and annealed at various temperatures B46 (1990) 89
Donovan, E.P., see Hubler, G.K. B46 (1990) 384
Dooryhee, E., see Jollet, F. B46 (1990) 125
Dran, J.C., see Matzke, Hj. B46 (1990) 256
Dumoulin, L., see Bernas, H. B46 (1990) 269
Duraud, J.P., see Jollet, F. B46 (1990) 125
Dwivedi, K.K., see Chadderton, L.T. B46 (1990) 46

Eridon, J., see Özkan, H. B46 (1990) 202
Eridon, J., see Özkan, H. B46 (1990) 291
Eryu, O., see Masuda, K. B46 (1990) 284

Fallavier, M., see Davenas, J. B46 (1990) 317
Farlow, G.C., see O'Hern, M.E. B46 (1990) 171
Farlow, G.C. and L.A. Boatner, Ion irradiation effects for MgF_2 films on LiF substrates B46 (1990) 422
Fink, D., see Behar, M. B46 (1990) 313
Fink, D., K. Ibel, P. Goppelt, J.P. Biersack, L. Wang and M. Behar, Ion beam induced carbon clusters in polymers B46 (1990) 342
Fink, D., see Behar, M. B46 (1990) 350
Fink, D.W., see Chadderton, L.T. B46 (1990) 46
Fink, T., see Ravindra, N.M. B46 (1990) 409
Foad, M.A., see Glavas, E. B46 (1990) 156
Foti, A.M., F. Milano and L. Torrisi, Amino acid decomposition induced by keV ion irradiation B46 (1990) 361
Foti, G. and R. Reitano, Structure and bonding in ion irradiated polystyrene B46 (1990) 306
Foti, G., see Licciardello, A. B46 (1990) 338
Freire Jr., F.L., see Mariotto, G. B46 (1990) 107
Freire Jr, F.L., G. Della Mea, G. Mariotto, A. Miotello and F. Cervellera, Hydrogen analysis in sodium β''-alumina implanted with argon ions B46 (1990) 152
Friebele, E.J., see Tsai, T.E. B46 (1990) 265

Fuchs, G., see Donnet, C. B46 (1990) 89
Fuchs, G., see Abonneau, E. B46 (1990) 111
Fujihana, T., see Kobayashi, K. B46 (1990) 60

Garrison, B.J., see Smith, R. B46 (1990) 1
Gärtner, K., G. Götz, B. Weber, J. Danilovich and A. Novikov, Formation of a silicon/nitride layer system by N^+ implantation B46 (1990) 405
Gazecki, J., see Tay, M. B46 (1990) 379
Ghosh, S., see Chadderton, L.T. B46 (1990) 46
Glavas, E., P.D. Townsend and M.A. Foad, Refractive index changes in proton exchange $LiNbO_3$ by ion implantation B46 (1990) 156
Goppelt, P., see Fink, D. B46 (1990) 342
Götz, G., see Mühle, R. B46 (1990) 347
Götz, G., see Gärtner, K. B46 (1990) 405
Greegor, R.B., see Weber, W.J. B46 (1990) 160
Griscom, D.L., Growth and decay kinetics of defect centers in high-purity fused silicas irradiated at 77 K with X-rays or 6.4-eV laser light B46 (1990) 12
Griscom, D.L., see Tsai, T.E. B46 (1990) 265
Grob, J.J., see Toulemonde, M. B46 (1990) 64
Gualtieri, J.G., see Ravindra, N.M. B46 (1990) 409
Guimarães, R.B., see Behar, M. B46 (1990) 313
Guimarães, R.B., see Behar, M. B46 (1990) 350

Hage-Ali, M., see Toulemonde, M. B46 (1990) 64
Harrison Jr., D.E., see Smith, R. B46 (1990) 1
Hill, I., see Lehockey, E.M. B46 (1990) 364
Hillairet, J., see Macchi, F. B46 (1990) 334
Hohmuth, K. and B. Rauschenbach, Superconducting and structural properties of Y–Ba–Cu oxide thin films prepared by ion beam mixing B46 (1990) 276
Hubler, G.K., C.A. Carosella, E.P. Donovan, D. Vanvechten, R.H. Bassel, T.D. Andreadis, M. Rosen and G.P. Mueller, Physical aspects of ion beam assisted deposition B46 (1990) 384

Ibel, K., see Fink, D. B46 (1990) 342
Itoh, N., see Tanimura, K. B46 (1990) 207
Iwaki, M., see Kobayashi, K. B46 (1990) 60
Iwaki, M., see Aono, K. B46 (1990) 220
Iwaki, M., see Suzuki, Y. B46 (1990) 354
Iwaki, M., see Ohira, S. B46 (1990) 413

Jaffrezic, H., see Donnet, C. B46 (1990) 89
Jollet, F., J.P. Duraud, C. Noguera, E. Dooryhee and Y. Langevin, Surface modifications of crystalline SiO_2 and Al_2O_3 induced by energetic heavy ions B46 (1990) 125
Jones, S.C., see Braunlich, P. B46 (1990) 224
Jones, S.C., see Casper, R.T. B46 (1990) 231
Joslin, D.L., see McHargue, C.J. B46 (1990) 185

Kallweit, R., see Biersack, J.P. B46 (1990) 309
Karioris, F.G., H. Özkan, S.B. Luyckx and L. Cartz, The stability of WC to ion bombardment B46 (1990) 176
Karioris, F.G., see Özkan, H. B46 (1990) 202
Karioris, F.G., see Özkan, H. B46 (1990) 291
Kaschny, J., see Behar, M. B46 (1990) 313
Kaufman, J.J., see Li, J. B46 (1990) 287
Kelly, P., see Braunlich, P. B46 (1990) 224
Kelly, P., see Casper, R.T. B46 (1990) 231
Kelly, R., Thermal sputtering as a gas-dynamic process B46 (1990) 441
Khodr, C., see Davenas, J. B46 (1990) 417
Kobayashi, K., S. Namba, T. Fujihana, K. Yabe and M. Iwaki, Relation between composition and structure of N-implanted AlN_x B46 (1990) 60
Kojima, S., see Zinkle, S.J. B46 (1990) 165
Kusakabe, M., see Suzuki, Y. B46 (1990) 354

Langevin, Y., see Jollet, F. . . . B46 (1990) 125
Lareau, R.T., see Ravindra, N.M. . . . B46 (1990) 409
Lauzier, J., see Macchi, F. . . . B46 (1990) 334
Lefrant, S., see Bernard, M. . . . B46 (1990) 235
Legrand, J.F., see Macchi, F. . . . B46 (1990) 324
Legrand, J.F., see Macchi, F. . . . B46 (1990) 334
Lehockey, E.M., I. Reid and I. Hill, Physical and chemical aspects of PMMA vapour development . . . B46 (1990) 364
Lekala, L.M., see Luyckx, S.B. . . . B46 (1990) 36
Lesueur, J., see Bernas, H. . . . B46 (1990) 269
Leung, C.H., see Chen, L.F. . . . B46 (1990) 216
Li, J., L.J. Matienzo, P. Revesz, Gy. Vizkelethy, S.Q. Wang, J.J. Kaufman and J.W. Mayer, Oxygen depth profiling study of copper oxide films on silicon (100) substrates by $^{16}O(\alpha, \alpha)^{16}O$ resonance . . . B46 (1990) 287
Licciardello, A., O. Puglisi, L. Calcagno and G. Foti, Crosslinking yield in particle beam irradiated polystyrene . B46 (1990) 338
Linker, G., see Matzke, Hj. . . . B46 (1990) 256
Lu, X.L., see Davenas, J. . . . B46 (1990) 317
Lux, R., see Ravindra, N.M. . . . B46 (1990) 409
Luyckx, S.B., L.M. Lekala and T.E. Derry, On the calculation of stresses induced by ion implantation . . . B46 (1990) 36
Luyckx, S.B., see Karioris, F.G. . . . B46 (1990) 176

Macaulay-Newcombe, R.G., D.A. Thompson, J.A. Davies and D.V. Stevanovic, Ion-beam damage to quartz crystals . . . B46 (1990) 180
Macchi, F., B. Daudin and J.F. Legrand, Electron irradiation induced structural modifications in ferroeletric P(VDF–TrFE) copolymers . . . B46 (1990) 324
Macchi, F., B. Daudin, J. Hillairet, J. Lauzier, J.B. N'Goma, J.Y. Cavaille and J.F. Legrand, Micromechanical properties of electron irradiated PVDF–TrFE copolymers . . . B46 (1990) 334
Magnera, T.F., see Balaji, V. . . . B46 (1990) 435
Marest, G., see McHargue, C.J. . . . B46 (1990) 74
Marest, G., see McHargue, C.J. . . . B46 (1990) 144
Mariotto, G., A. Miotello, G. Della Mea and F.L. Freire Jr, Sodium transport in β''-alumina crystals under argon ion bombardment . . . B46 (1990) 107
Mariotto, G., see Freire Jr., F.L. . . . B46 (1990) 152
Marletta, G., Chemical reactions and physical property modifications induced by keV ion beams in polymers . . B46 (1990) 295
Massouras, G., see Romana, L. . . . B46 (1990) 94
Masuda, K., O. Eryu, K. Murakami and K. Takita, Ion implantation effect in high T_c oxide $Y_1Ba_2Cu_3O_y$ . . . B46 (1990) 284
Matienzo, L.J., see Li, J. . . . B46 (1990) 287
Matsunami, N., The role of electronic excitation in ion-induced erosion of frozen gases . . . B46 (1990) 452
Matzke, Hj. and A. Turos, A channeling study of ion implantation damage in UO_2 and UN . . . B46 (1990) 117
Matzke, Hj., G. Della Mea, J.C. Dran, G. Linker and B. Tiveron, Radiation damage in nuclear waste glasses following ion implantation at different temperatures . . . B46 (1990) 256
Mayer, J.W., see Li, J. . . . B46 (1990) 287
McCallum, J.C., see McHargue, C.J. . . . B46 (1990) 74
McCallum, J.C., J. Rankin, C.W. White and L.A. Boatner, Time resolved reflectivity measurements in Pb-implanted $SrTiO_3$ . . . B46 (1990) 98
McCallum, J.C., see Sklad, P.S. . . . B46 (1990) 102
McCallum, J.C., C.W. White, P.S. Sklad and C.J. McHargue, Annealing environment effects in solid-phase epitaxial regrowth of Fe-implanted Al_2O_3 . . . B46 (1990) 137
McCallum, J.C., see McHargue, C.J. . . . B46 (1990) 144
McCubbery, M.D., see Tay, M. . . . B46 (1990) 379
McHargue, C.J., P.S. Sklad, J.C. McCallum, C.W. White, A. Perez, E. Abonneau and G. Marest, The residual charge state of tin implanted into sapphire . . . B46 (1990) 74
McHargue, C.J., P.S. Sklad and C.W. White, The structure of ion implanted ceramics . . . B46 (1990) 79
McHargue, C.J., see Sklad, P.S. . . . B46 (1990) 102
McHargue, C.J., see McCallum, J.C. . . . B46 (1990) 137
McHargue, C.J., P.S. Sklad, J.C. McCallum, C.W. White, A. Perez and G. Marest, The structure of Al_2O_3 implanted with iron at 77 K . . . B46 (1990) 144
McHargue, C.J., D.L. Joslin and J.M. Williams, The hardness and elastic modulus of chromium-implanted silicon carbide . . . B46 (1990) 185
McHargue, C.J., see Pawel, J.E. . . . B46 (1990) 392
McHargue, G.J., see O'Hern, M.E. . . . B46 (1990) 171
Michl, J., see Balaji, V. . . . B46 (1990) 435
Milano, F., see Foti, A.M. . . . B46 (1990) 361

Miotello, A., see Mariotto, G. B46 (1990) 107
Miotello, A., see Freire Jr., F.L. B46 (1990) 152
Moncoffre, N., see Donnet, C. B46 (1990) 89
Moncoffre, N., see Canut, B. B46 (1990) 128
Mueller, G.P., see Hubler, G.K. B46 (1990) 384
Mühle, R. and G. Götz, Ion beam exposure characteristics of nitrocellulose B46 (1990) 347
Murakami, K., see Masuda, K. B46 (1990) 284
Murphy, M.J., see Wood, R.A. B46 (1990) 189

Namba, S., see Kobayashi, K. B46 (1990) 60
Namba, S., see Aono, K. B46 (1990) 220
Nédellec, P., see Bernas, H. B46 (1990) 269
N'Goma, J.B., see Macchi, F. B46 (1990) 334
Noguera, C., see Jollet, F. B46 (1990) 125
Novikov, A., see Gärtner, K. B46 (1990) 405

O'Hern, M.E., G.J. McHargue, C.W. White and G.C. Farlow, The effect of chromium implantation on the hardness, elastic modulus and residual stress of Al_2O_3 . . . . . B46 (1990) 171
Ohira, S. and M. Iwaki, Oxygen irradiation effect in ion-beam-synthesized aluminium oxide layers B46 (1990) 413
Oliva, A., see Bonanno, A. B46 (1990) 456
Özkan, H., see Karioris, F.G. B46 (1990) 176
Özkan, H., F.G. Karioris, J. Eridon and L. Cartz, Radiation damage of lithium ceramics by ion bombardment . B46 (1990) 202
Özkan, H., F.G. Karioris, E.R. Vance, J. Eridon and L. Cartz, Damage of $YBa_2C_3O_x$ by ion irradiation B46 (1990) 291

Parkin, D.M., The displacement cascade in ceramic oxides B46 (1990) 26
Pawel, J.E., C.J. McHargue and J.J. Wert, The influence of ion bombardment on the adhesion of thin films to substrates B46 (1990) 392
Pells, G.P., see Wood, R.A. B46 (1990) 189
Perez, A., see McHargue, C.J. B46 (1990) 74
Perez, A., see Abonneau, E. B46 (1990) 111
Perez, A., see McHargue, C.J. B46 (1990) 144
Pfeffer, R.L., see Ravindra, N.M. B46 (1990) 409
Puglisi, O., see Licciardello, A. B46 (1990) 338

Ramola, R.C., see Sandhu, A.S. B46 (1990) 122
Rankin, J., see McCallum, J.C. B46 (1990) 98
Rauschenbach, B., see Hohmuth, K. B46 (1990) 276
Ravindra, N.M., T. Fink, W. Savin, T.P. Sjoreen, R.L. Pfeffer, L.G. Yerke, R.T. Lareau, J.G. Gualtieri, R. Lux and C. Wrenn, Oxygen ion implanted germanium – structural properties B46 (1990) 409
Reid, I., see Lehockey, E.M. B46 (1990) 364
Reitano, R., see Foti, G. B46 (1990) 306
Revesz, P., see Li, J. B46 (1990) 287
Romana, L., P. Thevenard, B. Canut, G. Massouras, R. Brenier and M. Brunel, Phase formation study in α-Al_2O_3 implanted with niobium ions B46 (1990) 94
Romana, L., see Canut, B. B46 (1990) 128
Rosen, M., see Hubler, G.K. B46 (1990) 384
Ruault, M.O., see Bernas, H. B46 (1990) 269
Rye, R.R., see Arnold, G.W. B46 (1990) 330
Rzepka, E., see Bernard, M. B46 (1990) 235

Sandhu, A.S., L. Singh, R.C. Ramola, S. Singh and H.S. Virk, Annealing kinetics of heavy ion radiation damage in crystalline minerals B46 (1990) 122
Sandhu, A.S., see Singh, L. B46 (1990) 149
Savin, W., see Ravindra, N.M. B46 (1990) 409
Sawicka, B.D., see Sawicki, J.A. B46 (1990) 38
Sawicki, J.A. and B.D. Sawicka, Properties of ^{57}Fe hot-implanted into diamond crystals studied by Mössbauer emission spectroscopy between 4 and 300 K B46 (1990) 38
Saxena, A., see Chadderton, L.T. B46 (1990) 46
Shen, X.-A., see Braunlich, P. B46 (1990) 224
Singh, L., see Sandhu, A.S. B46 (1990) 122
Singh, L., A.S. Sandhu, S. Singh and H.S. Virk, Etching and annealing kinetics of heavy ion tracks in quartz crystal B46 (1990) 149

Singh, R.C., see Bhatia, R.K. . . . B46 (1990) 358
Singh, S., see Sandhu, A.S. . . . B46 (1990) 122
Singh, S., see Singh, L. . . . B46 (1990) 149
Sjoreen, T.P., see Ravindra, N.M. . . . B46 (1990) 409
Sklad, P.S., see McHargue, C.J. . . . B46 (1990) 74
Sklad, P.S., see McHargue, C.J. . . . B46 (1990) 79
Sklad, P.S., J.C. McCallum, C.J. McHargue and C.W. White, The amorphous-to-gamma transformation in ion implanted Al_2O_3 . . . B46 (1990) 102
Sklad, P.S., see McCallum, J.C. . . . B46 (1990) 137
Sklad, P.S., see McHargue, C.J. . . . B46 (1990) 144
Smith, R., D.E. Harrison Jr and B.J. Garrison, Simulation of keV particle bombardment of covalent materials: an investigation of the yield dependence on incidence angle . . . B46 (1990) 1
Song, K.S., see Chen, L.F. . . . B46 (1990) 216
Sood, D.K. and D.X. Cao, Annealing behaviour of *a*-axis sapphire amorphized by high dose indium ion implantation . . . B46 (1990) 194
Sosnowski, M. and I. Yamada, Ionized cluster beam deposition and thin insulating films . . . B46 (1990) 397
Stevanovic, D.V., see Macaulay-Newcombe, R.G. . . . B46 (1990) 180
Stoquert, J.P., see Toulemonde, M. . . . B46 (1990) 64
Suzuki, Y., C. Swapp, M. Kusakabe and M. Iwaki, Aging effects on wettability and structure of ion implanted silicone . . . B46 (1990) 354
Swapp, C., see Suzuki, Y. . . . B46 (1990) 354
Szymonski, M., Current views on electronic and cascade sputtering of alkali halides . . . B46 (1990) 427

Takita, K., see Masuda, K. . . . B46 (1990) 284
Tanimura, K. and N. Itoh, The role of self-trapped excitons in radiation-damage processes in insulators . . . B46 (1990) 207
Tay, M., J. Gazecki, M.D. McCubbery and J.S. Williams, Influence of low energy electron irradiation on adhesion and electrical parameters of metal–insulator–GaAs interfaces . . . B46 (1990) 379
Thevenard, P., see Romana, L. . . . B46 (1990) 94
Thevenard, P., see Canut, B. . . . B46 (1990) 128
Thevenard, P., see Davenas, J. . . . B46 (1990) 317
Thevenard, P., see Davenas, J. . . . B46 (1990) 417
Thompson, D.A., see Macaulay-Newcombe, R.G. . . . B46 (1990) 180
Tiveron, B., see Matzke, Hj. . . . B46 (1990) 256
Torrisi, L., see Foti, A.M. . . . B46 (1990) 361
Toulemonde, M., E. Balanzat, S. Bouffard, J.J. Grob, M. Hage-Ali and J.P. Stoquert, Damage induced by high electronic stopping power in SiO_2 quartz . . . B46 (1990) 64
Tousset, J., see Donnet, C. . . . B46 (1990) 89
Townsend, P.D., An overview of ion-implanted optical waveguide profiles . . . B46 (1990) 18
Townsend, P.D., see Chandler, P.J. . . . B46 (1990) 69
Townsend, P.D., see Al Ghamdi, A. . . . B46 (1990) 133
Townsend, P.D., see Glavas, E. . . . B46 (1990) 156
Townsend, P.D., see Wood, R.A. . . . B46 (1990) 189
Treilleux, M., see Abonneau, E. . . . B46 (1990) 111
Tsai, T.E., D.L. Griscom and E.J. Friebele, Si E′ centers and UV-induced compaction in high purity silica . . . B46 (1990) 265
Turos, A., see Matzke, Hj. . . . B46 (1990) 117

Urbassek, H.M., see Balaji, V. . . . B46 (1990) 435

Vance, E.R., see Özkan, H. . . . B46 (1990) 291
Vanvechten, D., see Hubler, G.K. . . . B46 (1990) 384
Virk, H.S., see Sandhu, A.S. . . . B46 (1990) 122
Virk, H.S., see Singh, L. . . . B46 (1990) 149
Virk, H.S., see Bhatia, R.K. . . . B46 (1990) 358
Vizkelethy, Gy., see Li, J. . . . B46 (1990) 287

Wang, L., see Fink, D. . . . B46 (1990) 342
Wang, S.Q., see Li, J. . . . B46 (1990) 287
Weber, B., see Gärtner, K. . . . B46 (1990) 405
Weber, W.J. and R.B. Greegor, Alpha irradiation effects in $Ca_2Nd_8(SiO_4)_6O_2$ . . . B46 (1990) 160
Wert, J.J., see Pawel, J.E. . . . B46 (1990) 392
White, C.W., see McHargue, C.J. . . . B46 (1990) 74
White, C.W., see McHargue, C.J. . . . B46 (1990) 79

White, C.W., see McCallum, J.C. B46 (1990) 98
White, C.W., see Sklad, P.S. B46 (1990) 102
White, C.W., see McCallum, J.C. B46 (1990) 137
White, C.W., see McHargue, C.J. B46 (1990) 144
White, C.W., see O'Hern, M.E. B46 (1990) 171
Williams, J.M., see McHargue, C.J. B46 (1990) 185
Williams, J.S., see Tay, M. B46 (1990) 379
Wolf, G.K., Modification of chemical surface properties by ion beam assisted deposition B46 (1990) 369
Wood, R.A., P.D. Townsend, G.P. Pells and M.J. Murphy, "Anomalous" fading in irradiated α-Al_2O_3 . . . . . B46 (1990) 189
Wrenn, C., see Ravindra, N.M. B46 (1990) 409

Yabe, K., see Kobayashi, K. B46 (1990) 60
Yamada, I., see Sosnowski, M. B46 (1990) 397
Yerke, L.G., see Ravindra, N.M. B46 (1990) 409

Zawislak, F.C., see Behar, M. B46 (1990) 313
Zawislak, F.C., see Behar, M. B46 (1990) 350
Zhang, L., see Chandler, P.J. B46 (1990) 69
Zinkle, S.J. and S. Kojima, Microstructural changes in $MgAl_2O_4$ induced by ion irradiation B46 (1990) 165